# LDO Regulator, 150 mA, Ultra-Low IQ, CMOS

The NCP170 series of CMOS low dropout regulators are designed specifically for portable battery-powered applications which require ultra-low quiescent current. The ultra-low consumption of typ. 500 nA ensures long battery life and dynamic transient boost feature improves device transient response for wireless communication applications. The device is available in small  $1 \times 1$  mm XDFN4, SOT-563 and TSOP-5 packages.

#### **Features**

- Operating Input Voltage Range: 2.2 V to 5.5 V
- Output Voltage Range: 1.2 V to 3.6 V (0.1 V Steps)
- Ultra-Low Quiescent Current Typ. 0.5 μA
- Low Dropout: 170 mV Typ. at 150 mA
- High Output Voltage Accuracy ±1%
- Stable with Ceramic Capacitors 1 µF
- Over-Current Protection
- Thermal Shutdown Protection
- NCP170A for Active Discharge Option
- Available in Small 1 × 1 mm XDFN4, SOT-563 and TSOP-5 **Packages**
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

#### **Typical Applications**

- Battery Powered Equipments
- Portable Communication Equipments
- Cameras, Image Sensors and Camcorders

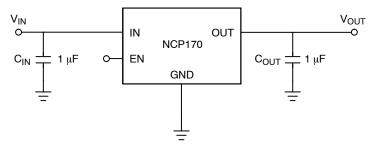


Figure 1. Typical Application Schematic



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XDFN4 **MX SUFFIX** CASE 711AJ

SOT-563 **XV SUFFIX** CASE 463A

TSOP-5 SN SUFFIX **CASE 483** 

#### **MARKING DIAGRAMS**



XX = Specific Device Code = Date Code

#### SOT-563



XX = Specific Device Code

= Month Code

= Pb-Free Package

\*Pb-Free indicator, "G" or microdot "=", may or may not be present.



XXX = Specific Device Code

= Assembly Location

= Year

= Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

See detailed ordering, marking and shipping information on page 21 of this data sheet.

#### **PIN FUNCTION DESCRIPTION**

| Pin No.<br>XDFN4 | Pin No.<br>SOT-563 | Pin No.<br>TSOP-5 | Pin Name | Description                  |
|------------------|--------------------|-------------------|----------|------------------------------|
| 4                | 1                  | 1                 | IN       | Power Supply Input Voltage   |
| 2                | 2                  | 2                 | GND      | Power Supply Ground          |
| 3                | 6                  | 3                 | EN       | Chip Enable Pin (Active "H") |
| 1                | 3                  | 5                 | OUT      | Output Pin                   |
| EPAD             | -                  | -                 | EPAD     | Internally Connected to GND  |
| -                | 4                  | 4                 | NC       | No Connect                   |
| _                | 5                  | -                 | GND      | Power Supply Ground          |

# **ABSOLUTE MAXIMUM RATINGS**

| Symbol              | Rating                                    | Value                         | Unit |
|---------------------|---|-------------------------------|------|
| V <sub>IN</sub>     | Input Voltage (Note 1)                    | 6.0                           | V    |
| V <sub>OUT</sub>    | Output Voltage                            | -0.3 to V <sub>IN</sub> + 0.3 | V    |
| V <sub>CE</sub>     | Chip Enable Input                         | -0.3 to 6.0                   | V    |
| T <sub>J(MAX)</sub> | Maximum Junction Temperature              | 150                           | °C   |
| T <sub>STG</sub>    | Storage Temperature                       | -55 to 150                    | °C   |
| ESD <sub>HBM</sub>  | ESD Capability, Human Body Model (Note 2) | 2000                          | V    |
| ESD <sub>MM</sub>   | ESD Capability, Machine Model (Note 2)    | 200                           | V    |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

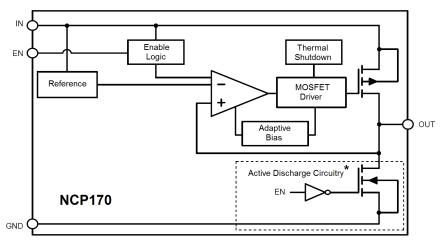
1. Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.

- 2. This device series incorporates ESD protection and is tested by the following methods:
  - ESD Human Body Model tested per AEC-Q100-002 (EIA/JESD22-A114) ESD Machine Model tested per AEC-Q100-003 (EIA/JESD22-A115)

Latchup Current Maximum Rating tested per JEDEC standard: JESD78

#### THERMAL CHARACTERISTICS

| Symbol        | Rating   | Value             | Unit |
|---------------|--|-------------------|------|
| $R_{	hetaJA}$ | Thermal Characteristics, Thermal Resistance, Junction-to-Air XDFN4 1 × 1 mm SOT–563 TSOP–5 | 250<br>200<br>250 | °C/W |



<sup>\*</sup> Active discharge feature is present only in NCP170AxxvvvTyG devices.

Figure 2. Simplified Block Diagram

#### **ELECTRICAL CHARACTERISTICS - VOLTAGE VERSION 1.2 V**

 $(-40^{\circ}C \leq T_{J} \leq 85^{\circ}C; \ V_{IN} = 2.5 \ V; \ I_{OUT} = 1 \ mA, \ C_{IN} = C_{OUT} = 1.0 \ \mu F, \ unless \ otherwise \ noted. \ Typical \ values \ are \ at \ T_{A} = +25^{\circ}C.) \ (Note \ 3)$ 

| Symbol              | Parameter   | Test Conditions   | Min      | Тур      | Max    | Unit  |
|---------------------|---|---|----------|----------|--------|-------|
| V <sub>IN</sub>     | Operating Input Voltage                               |   | 2.2      | -        | 5.5    | V     |
| V <sub>OUT</sub>    | Output Voltage  | T <sub>A</sub> = +25°C  | 1.188    | 1.2      | 1.212  | V     |
|                     |   | $-40^{\circ}\text{C} \le \text{T}_{\text{J}} \le 85^{\circ}\text{C}$  | 1.176    | 1.2      | 1.224  |       |
| Line <sub>Reg</sub> | Line Regulation                                       | 2.5 V < V <sub>IN</sub> ≤ 5.5 V, I <sub>OUT</sub> = 1 mA  | _        | 0.05     | 0.20   | %/V   |
| Load <sub>Reg</sub> | Load Regulation                                       | 0 mA < $I_{OUT} \le$ 150 mA, $V_{IN} = 2.5 \text{ V}$   | -20      | 1        | 20     | mV    |
| $V_{DO}$            | Dropout Voltage                                       | (Note 4)  | _        | -        | -      | mV    |
| I <sub>OUT</sub>    | Output Current  | (Note 5)  | 150      | -        | -      | mA    |
| I <sub>SC</sub>     | Short Circuit Current Limit                           | V <sub>OUT</sub> = 0 V  | _        | 225      | -      | mA    |
| IQ                  | Quiescent Current                                     | I <sub>OUT</sub> = 0 mA   | _        | 0.5      | 0.9    | μΑ    |
| I <sub>STB</sub>    | Standby Current                                       | V <sub>EN</sub> = 0 V, T <sub>J</sub> = 25°C  | _        | 0.1      | 0.5    | μΑ    |
| V <sub>ENH</sub>    | EN Pin Threshold Voltage                              | EN Input Voltage "H"  | 1.2      | -        | -      | V     |
| V <sub>ENL</sub>    | EN Pin Threshold Voltage                              | EN Input Voltage "L"  | _        | -        | 0.4    | V     |
| I <sub>EN</sub>     | EN Pin Current  | V <sub>EN</sub> ≤ V <sub>IN</sub> ≤ 5.5 V (Note 6)  | -        | 10       | -      | nA    |
| PSRR                | Power Supply Rejection Ratio                          | $ f = 1 \text{ kHz, V}_{\text{IN}} = 2.2 \text{ V} + 200 \text{ mVpp Modulation} $ $ I_{\text{OUT}} = 150 \text{ mA} $ $ I_{\text{OUT}} = 10 \text{ mA} $ | <u>-</u> | 57<br>63 | _<br>_ | dB    |
| V <sub>NOISE</sub>  | Output Noise Voltage                                  | $V_{IN}$ = 5.5 V, $I_{OUT}$ = 1 mA, f = 100 Hz to 1 MHz, $C_{OUT}$ = 1 $\mu F$  | -        | 85       | -      | μVrms |
| R <sub>LOW</sub>    | Active Output Discharge<br>Resistance (A option only) | V <sub>IN</sub> = 5.5 V, V <sub>EN</sub> = 0 V (Note 6)   | -        | 100      | _      | Ω     |
| $T_{SD}$            | Thermal Shutdown Temperature                          | Temperature Increasing from T <sub>J</sub> = +25°C (Note 6)   | -        | 175      | _      | °C    |
| T <sub>SDH</sub>    | Thermal Shutdown Hysteresis                           | Temperature Falling from T <sub>SD</sub> (Note 6)   | -        | 25       | -      | °C    |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Performance guaranteed over the indicated operating temperature range by design and/or characterization production tested at T<sub>J</sub> = T<sub>A</sub> = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.
 No T<sub>A</sub> = 20°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.
 No T<sub>A</sub> = 20°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.

<sup>5.</sup> Respect SOA.

<sup>6.</sup> Guaranteed by design and characterization.

# **ELECTRICAL CHARACTERISTICS - VOLTAGE VERSION 1.5 V**

 $(-40^{\circ}C \leq T_{J} \leq 85^{\circ}C; \ V_{IN} = 2.5 \ V; \ I_{OUT} = 1 \ mA, \ C_{IN} = C_{OUT} = 1.0 \ \mu F, \ unless \ otherwise \ noted. \ Typical \ values \ are \ at \ T_{A} = +25^{\circ}C.) \ (Note \ 7) \ ($ 

| Symbol              | Parameter   | Test Conditions  | Min   | Тур  | Max   | Unit  |
|---------------------|---|--|-------|------|-------|-------|
| V <sub>IN</sub>     | Operating Input Voltage                               |  | 2.2   | -    | 5.5   | V     |
| V <sub>OUT</sub>    | Output Voltage  | T <sub>A</sub> = +25°C   | 1.485 | 1.5  | 1.515 | V     |
|                     |   | $-40^{\circ}\text{C} \le \text{T}_{\text{J}} \le 85^{\circ}\text{C}$                                       | 1.470 | 1.5  | 1.530 |       |
| Line <sub>Reg</sub> | Line Regulation                                       | 4.3 V < V <sub>IN</sub> ≤ 5.5 V, I <sub>OUT</sub> = 1 mA   | -     | 0.05 | 0.20  | %/V   |
| Load <sub>Reg</sub> | Load Regulation                                       | 0 mA < $I_{OUT} \le$ 150 mA, $V_{IN} = 4.3 \text{ V}$  | -20   | -    | 20    | mV    |
| V <sub>DO</sub>     | Dropout Voltage                                       | I <sub>OUT</sub> = 150 mA (Note 8)   | -     | -    | -     | mV    |
| I <sub>OUT</sub>    | Output Current  | (Note 9)   | 150   | -    | -     | mA    |
| I <sub>SC</sub>     | Short Circuit Current Limit                           | V <sub>OUT</sub> = 0 V   | _     | 225  | -     | mA    |
| IQ                  | Quiescent Current                                     | I <sub>OUT</sub> = 0 mA  | _     | 0.5  | 0.9   | μΑ    |
| I <sub>STB</sub>    | Standby Current                                       | V <sub>EN</sub> = 0 V, T <sub>J</sub> = 25°C   | _     | 0.1  | 0.5   | μΑ    |
| V <sub>ENH</sub>    | EN Pin Threshold Voltage                              | EN Input Voltage "H"   | 1.2   | -    | -     | V     |
| V <sub>ENL</sub>    | EN Pin Threshold Voltage                              | EN Input Voltage "L"   | _     | -    | 0.4   | V     |
| I <sub>EN</sub>     | EN Pin Current  | V <sub>EN</sub> ≤ V <sub>IN</sub> ≤ 5.5 V (Note 10)  | -     | 10   | -     | nA    |
| PSRR                | Power Supply Rejection Ratio                          | $f = 1 \text{ kHz}$ , $V_{IN} = 2.5 \text{ V} + 200 \text{ mVpp Modulation}$<br>$I_{OUT} = 150 \text{ mA}$ | -     | 57   | -     | dB    |
| V <sub>NOISE</sub>  | Output Noise Voltage                                  | $V_{IN}$ = 5.5 V, $I_{OUT}$ = 1 mA, f = 100 Hz to 1 MHz, $C_{OUT}$ = 1 $\mu F$                             | -     | 90   | -     | μVrms |
| R <sub>LOW</sub>    | Active Output Discharge<br>Resistance (A option only) | V <sub>IN</sub> = 5.5 V, V <sub>EN</sub> = 0 V (Note 10)   | -     | 100  | -     | Ω     |
| T <sub>SD</sub>     | Thermal Shutdown Temperature                          | Temperature Increasing from T <sub>J</sub> = +25°C (Note 10)   | -     | 175  | -     | °C    |
| T <sub>SDH</sub>    | Thermal Shutdown Hysteresis                           | Temperature Falling from T <sub>SD</sub> (Note 10)   | -     | 25   | -     | °C    |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

7. Performance guaranteed over the indicated operating temperature range by design and/or characterization production tested at

T<sub>J</sub> = T<sub>A</sub> = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.

Not Characterized at V<sub>IN</sub> = 2.2 V, V<sub>OUT</sub> = 1.5 V, I<sub>OUT</sub> = 150 mA.

<sup>10.</sup> Guaranteed by design and characterization.

# **ELECTRICAL CHARACTERISTICS - VOLTAGE VERSION 1.8 V**

 $(-40^{\circ}C \leq T_{J} \leq 85^{\circ}C; \ V_{IN} = 2.8 \ V; \ I_{OUT} = 1 \ mA, \ C_{IN} = C_{OUT} = 1.0 \ \mu F, \ unless otherwise noted. Typical values are at T_{A} = +25^{\circ}C.) \ (Note \ 11) = 1.0 \ \mu F$ 

| Symbol              | Parameter   | Test Conditions   | Min   | Тур  | Max   | Unit  |
|---------------------|---|---|-------|------|-------|-------|
| V <sub>IN</sub>     | Operating Input Voltage                               |   | 2.2   | -    | 5.5   | V     |
|                     |   | I <sub>OUT</sub> < 30 mA  | 2.0   | -    | 5.5   |       |
| V <sub>OUT</sub>    | Output Voltage  | T <sub>A</sub> = +25°C  | 1.782 | 1.8  | 1.818 | V     |
|                     |   | $-40^{\circ}\text{C} \le \text{T}_{\text{J}} \le 85^{\circ}\text{C}$          | 1.764 | 1.8  | 1.836 |       |
| Line <sub>Reg</sub> | Line Regulation                                       | 2.8 V < V <sub>IN</sub> ≤ 5.5 V, I <sub>OUT</sub> = 1 mA                      | _     | 0.05 | 0.20  | %/V   |
| Load <sub>Reg</sub> | Load Regulation                                       | 0 mA < $I_{OUT} \le$ 150 mA, $V_{IN} = 2.8 \text{ V}$                         | -20   | 1    | 20    | mV    |
| $V_{DO}$            | Dropout Voltage                                       | I <sub>OUT</sub> = 150 mA (Note 12)   | -     | 350  | 480   | mV    |
| I <sub>OUT</sub>    | Output Current  | (Note 13)   | 150   | -    | -     | mA    |
| I <sub>SC</sub>     | Short Circuit Current Limit                           | V <sub>OUT</sub> = 0 V  | -     | 225  | -     | mA    |
| IQ                  | Quiescent Current                                     | I <sub>OUT</sub> = 0 mA   | -     | 0.5  | 0.9   | μΑ    |
| I <sub>STB</sub>    | Standby Current                                       | V <sub>EN</sub> = 0 V, T <sub>J</sub> = 25°C                                  | -     | 0.1  | 0.5   | μΑ    |
| V <sub>ENH</sub>    | EN Pin Threshold Voltage                              | EN Input Voltage "H"  | 1.2   | _    | -     | V     |
| V <sub>ENL</sub>    | EN Pin Threshold Voltage                              | EN Input Voltage "L"  | _     | _    | 0.4   | V     |
| I <sub>EN</sub>     | EN Pull Down Current                                  | V <sub>EN</sub> ≤ V <sub>IN</sub> ≤ 5.5 V (Note 14)                           | _     | 10   | -     | nA    |
| PSRR                | Power Supply Rejection Ratio                          | $f$ = 1 kHz, $V_{IN}$ = 2.8 V + 200 mVpp Modulation $I_{OUT}$ = 150 mA        | -     | 57   | -     | dB    |
| V <sub>NOISE</sub>  | Output Noise Voltage                                  | $V_{IN}$ = 5.5 V, $I_{OUT}$ = 1 mA f = 100 Hz to 1 MHz, $C_{OUT}$ = 1 $\mu F$ | -     | 95   | -     | μVrms |
| R <sub>LOW</sub>    | Active Output Discharge<br>Resistance (A option only) | V <sub>IN</sub> = 5.5 V, V <sub>EN</sub> = 0 V (Note 14)                      | -     | 100  | _     | Ω     |
| T <sub>SD</sub>     | Thermal Shutdown Temperature                          | Temperature Increasing from T <sub>J</sub> = +25°C (Note 14)                  | -     | 175  | -     | °C    |
| T <sub>SDH</sub>    | Thermal Shutdown Hysteresis                           | Temperature Falling from T <sub>SD</sub> (Note 14)                            | _     | 25   | -     | °C    |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

<sup>11.</sup> Performance guaranteed over the indicated operating temperature range by design and/or characterization production tested at  $T_J = T_A = 25^{\circ}$ C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible. 12. Characterized when  $V_{OUT}$  falls 54 mV below the regulated voltage and only for devices with  $V_{OUT} = 1.8$  V.

<sup>13.</sup> Respect SOA.

<sup>14.</sup> Guaranteed by design and characterization.

# **ELECTRICAL CHARACTERISTICS - VOLTAGE VERSION 2.5 V**

 $(-40^{\circ}C \leq T_{J} \leq 85^{\circ}C; \ V_{IN} = 3.5 \ V; \ I_{OUT} = 1 \ mA, \ C_{IN} = C_{OUT} = 1.0 \ \mu F, \ unless otherwise noted. Typical values are at T_{A} = +25^{\circ}C.) \ (Note 15)$ 

| Symbol              | Parameter   | Test Conditions   | Min   | Тур  | Max   | Unit  |
|---------------------|---|---|-------|------|-------|-------|
| V <sub>IN</sub>     | Operating Input Voltage                               |   | 2.2   | -    | 5.5   | V     |
| V <sub>OUT</sub>    | Output Voltage  | T <sub>A</sub> = +25°C  | 2.475 | 2.5  | 2.525 | V     |
|                     |   | -40°C ≤ T <sub>J</sub> ≤ 85°C   | 2.450 | 2.5  | 2.550 |       |
| Line <sub>Reg</sub> | Line Regulation                                       | 3.5 V < V <sub>IN</sub> ≤ 5.5 V, I <sub>OUT</sub> = 1 mA                      | -     | 0.05 | 0.20  | %/V   |
| Load <sub>Reg</sub> | Load Regulation                                       | 0 mA < $I_{OUT} \le$ 150 mA, $V_{IN} = 3.5 \text{ V}$                         | -20   | 1    | 20    | mV    |
| $V_{DO}$            | Dropout Voltage                                       | I <sub>OUT</sub> = 150 mA (Note 16)   | -     | 240  | 330   | mV    |
| I <sub>OUT</sub>    | Output Current  | (Note 17)   | 150   | -    | -     | mA    |
| I <sub>SC</sub>     | Short Circuit Current Limit                           | V <sub>OUT</sub> = 0 V  | -     | 225  | -     | mA    |
| IQ                  | Quiescent Current                                     | I <sub>OUT</sub> = 0 mA   | -     | 0.5  | 0.9   | μΑ    |
| I <sub>STB</sub>    | Standby Current                                       | V <sub>EN</sub> = 0 V, T <sub>J</sub> = 25°C                                  | -     | 0.1  | 0.5   | μΑ    |
| V <sub>ENH</sub>    | EN Pin Threshold Voltage                              | EN Input Voltage "H"  | 1.2   | -    | -     | V     |
| V <sub>ENL</sub>    | EN Pin Threshold Voltage                              | EN Input Voltage "L"  | -     | -    | 0.4   | V     |
| I <sub>EN</sub>     | EN Pull Down Current                                  | V <sub>EN</sub> ≤ V <sub>IN</sub> ≤ 5.5 V (Note 18)                           | -     | 10   | -     | nA    |
| PSRR                | Power Supply Rejection Ratio                          | $f$ = 1 kHz, $V_{IN}$ = 3.5 V + 200 mVpp Modulation $I_{OUT}$ = 150 mA        | -     | 57   | -     | dB    |
| V <sub>NOISE</sub>  | Output Noise Voltage                                  | $V_{IN}$ = 5.5 V, $I_{OUT}$ = 1 mA f = 100 Hz to 1 MHz, $C_{OUT}$ = 1 $\mu F$ | -     | 125  | -     | μVrms |
| $R_{LOW}$           | Active Output Discharge<br>Resistance (A option only) | V <sub>IN</sub> = 5.5 V, V <sub>EN</sub> = 0 V (Note 18)                      | -     | 100  | -     | Ω     |
| T <sub>SD</sub>     | Thermal Shutdown Temperature                          | Temperature Increasing from T <sub>J</sub> = +25°C (Note 18)                  | -     | 175  | -     | °C    |
| T <sub>SDH</sub>    | Thermal Shutdown Hysteresis                           | Temperature Falling from T <sub>SD</sub> (Note 18)                            | -     | 25   | -     | °C    |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product

performance may not be indicated by the Electrical Characteristics if operated under different conditions.

15. Performance guaranteed over the indicated operating temperature range by design and/or characterization production tested at  $T_J = T_A = 25^{\circ}$ C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible. 16. Characterized when  $V_{OUT}$  falls 75 mV below the regulated voltage and only for devices with  $V_{OUT} = 2.5$  V.

<sup>18.</sup> Guaranteed by design and characterization.

# **ELECTRICAL CHARACTERISTICS - VOLTAGE VERSION 2.8 V**

 $(-40^{\circ}C \leq T_{J} \leq 85^{\circ}C; \ V_{IN} = 3.8 \ V; \ I_{OUT} = 1 \ mA, \ C_{IN} = C_{OUT} = 1.0 \ \mu F, \ unless otherwise noted. Typical values are at T_{A} = +25^{\circ}C.) \ (Note 19)$ 

| Symbol              | Parameter   | Test Conditions   | Min   | Тур  | Max   | Unit  |
|---------------------|---|---|-------|------|-------|-------|
| V <sub>IN</sub>     | Operating Input Voltage                               |   | 2.2   | -    | 5.5   | V     |
| V <sub>OUT</sub>    | Output Voltage  | T <sub>A</sub> = +25°C  | 2.772 | 2.8  | 2.828 | V     |
|                     |   | $-40^{\circ}\text{C} \le \text{T}_{\text{J}} \le 85^{\circ}\text{C}$          | 2.744 | 2.8  | 2.856 |       |
| Line <sub>Reg</sub> | Line Regulation                                       | 3.8 V < V <sub>IN</sub> ≤ 5.5 V, I <sub>OUT</sub> = 1 mA                      | -     | 0.05 | 0.20  | %/V   |
| Load <sub>Reg</sub> | Load Regulation                                       | 0 mA < $I_{OUT} \le$ 150 mA, $V_{IN} = 3.8 \text{ V}$                         | -20   | 1    | 20    | mV    |
| V <sub>DO</sub>     | Dropout Voltage                                       | I <sub>OUT</sub> = 150 mA (Note 20)   | -     | 210  | 300   | mV    |
| I <sub>OUT</sub>    | Output Current  | (Note 21)   | 150   | -    | -     | mA    |
| I <sub>SC</sub>     | Short Circuit Current Limit                           | V <sub>OUT</sub> = 0 V  | _     | 195  | -     | mA    |
| IQ                  | Quiescent Current                                     | I <sub>OUT</sub> = 0 mA   | _     | 0.5  | 0.9   | μА    |
| I <sub>STB</sub>    | Standby Current                                       | V <sub>EN</sub> = 0 V, T <sub>J</sub> = 25°C                                  | _     | 0.1  | 0.5   | μА    |
| V <sub>ENH</sub>    | EN Pin Threshold Voltage                              | EN Input Voltage "H"  | 1.2   | -    | -     | V     |
| V <sub>ENL</sub>    | EN Pin Threshold Voltage                              | EN Input Voltage "L"  | _     | -    | 0.4   | V     |
| I <sub>EN</sub>     | EN Pull Down Current                                  | V <sub>EN</sub> ≤ V <sub>IN</sub> ≤ 5.5 V (Note 22)                           | _     | 10   | _     | nA    |
| PSRR                | Power Supply Rejection Ratio                          | $f$ = 1 kHz, $V_{IN}$ = 3.8 V + 200 mVpp Modulation $I_{OUT}$ = 150 mA        | -     | 40   | -     | dB    |
| V <sub>NOISE</sub>  | Output Noise Voltage                                  | $V_{IN}$ = 5.5 V, $I_{OUT}$ = 1 mA f = 100 Hz to 1 MHz, $C_{OUT}$ = 1 $\mu F$ | -     | 125  | -     | μVrms |
| R <sub>LOW</sub>    | Active Output Discharge<br>Resistance (A option only) | V <sub>IN</sub> = 5.5 V, V <sub>EN</sub> = 0 V (Note 22)                      | -     | 100  | -     | Ω     |
| T <sub>SD</sub>     | Thermal Shutdown Temperature                          | Temperature Increasing from T <sub>J</sub> = +25°C (Note 22)                  | -     | 175  | -     | °C    |
| T <sub>SDH</sub>    | Thermal Shutdown Hysteresis                           | Temperature Falling from T <sub>SD</sub> (Note 22)                            | -     | 25   | -     | °C    |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

19.Performance guaranteed over the indicated operating temperature range by design and/or characterization production tested at

<sup>19.</sup>Performance guaranteed over the indicated operating temperature range by design and/or characterization production tested at T<sub>J</sub> = T<sub>A</sub> = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible. 20.Characterized when V<sub>OUT</sub> falls 84 mV below the regulated voltage and only for devices with V<sub>OUT</sub> = 2.8 V.

<sup>21.</sup> Respect SOA

 $<sup>\</sup>ensuremath{\text{22.}}\xspace$  Guaranteed by design and characterization.

# **ELECTRICAL CHARACTERISTICS - VOLTAGE VERSION 3.0 V**

 $(-40^{\circ}C \leq T_{J} \leq 85^{\circ}C; \ V_{IN} = 4.0 \ V; \ I_{OUT} = 1 \ mA, \ C_{IN} = C_{OUT} = 1.0 \ \mu F, \ unless otherwise noted. Typical values are at T_{A} = +25^{\circ}C.) \ (Note 23)$ 

| Symbol              | Parameter   | Test Conditions   | Min  | Тур  | Max  | Unit  |
|---------------------|---|---|------|------|------|-------|
| V <sub>IN</sub>     | Operating Input Voltage                               |   | 2.2  | -    | 5.5  | V     |
| V <sub>OUT</sub>    | Output Voltage  | T <sub>A</sub> = +25°C  | 2.97 | 3.0  | 3.03 | V     |
|                     |   | $-40^{\circ}\text{C} \le \text{T}_{\text{J}} \le 85^{\circ}\text{C}$          | 2.94 | 3.0  | 3.06 |       |
| Line <sub>Reg</sub> | Line Regulation                                       | 4.0 V < V <sub>IN</sub> ≤ 5.5 V, I <sub>OUT</sub> = 1 mA                      | -    | 0.05 | 0.20 | %/V   |
| Load <sub>Reg</sub> | Load Regulation                                       | 0 mA < $I_{OUT} \le$ 150 mA, $V_{IN} = 4 \text{ V}$                           | -20  | 1    | 20   | mV    |
| $V_{DO}$            | Dropout Voltage                                       | I <sub>OUT</sub> = 150 mA (Note 24)   | -    | 190  | 260  | mV    |
| I <sub>OUT</sub>    | Output Current  | (Note 25)   | 150  | -    | -    | mA    |
| I <sub>SC</sub>     | Short Circuit Current Limit                           | V <sub>OUT</sub> = 0 V  | -    | 195  | -    | mA    |
| IQ                  | Quiescent Current                                     | I <sub>OUT</sub> = 0 mA   | -    | 0.5  | 0.9  | μΑ    |
| I <sub>STB</sub>    | Standby Current                                       | V <sub>EN</sub> = 0 V, T <sub>J</sub> = 25°C                                  | -    | 0.1  | 0.5  | μΑ    |
| V <sub>ENH</sub>    | EN Pin Threshold Voltage                              | EN Input Voltage "H"  | 1.2  | -    | -    | V     |
| V <sub>ENL</sub>    | EN Pin Threshold Voltage                              | EN Input Voltage "L"  | -    | -    | 0.4  | V     |
| I <sub>EN</sub>     | EN Pull Down Current                                  | V <sub>EN</sub> ≤ V <sub>IN</sub> ≤ 5.5 V (Note 26)                           | -    | 10   | -    | nA    |
| PSRR                | Power Supply Rejection Ratio                          | $f$ = 1 kHz, $V_{IN}$ = 4.0 V + 200 mVpp Modulation $I_{OUT}$ = 150 mA        | -    | 47   | -    | dB    |
| V <sub>NOISE</sub>  | Output Noise Voltage                                  | $V_{IN}$ = 5.5 V, $I_{OUT}$ = 1 mA f = 100 Hz to 1 MHz, $C_{OUT}$ = 1 $\mu F$ | -    | 120  | -    | μVrms |
| $R_{LOW}$           | Active Output Discharge<br>Resistance (A option only) | V <sub>IN</sub> = 5.5 V, V <sub>EN</sub> = 0 V (Note 26)                      | =    | 100  | _    | Ω     |
| T <sub>SD</sub>     | Thermal Shutdown Temperature                          | Temperature Increasing from T <sub>J</sub> = +25°C (Note 26)                  | -    | 175  | -    | °C    |
| T <sub>SDH</sub>    | Thermal Shutdown Hysteresis                           | Temperature Falling from T <sub>SD</sub> (Note 26)                            | _    | 25   | -    | °C    |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product

performance may not be indicated by the Electrical Characteristics if operated under different conditions.

23. Performance guaranteed over the indicated operating temperature range by design and/or characterization production tested at  $T_J = T_A = 25^{\circ}$ C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible. 24. Characterized when  $V_{OUT}$  falls 90 mV below the regulated voltage and only for devices with  $V_{OUT} = 3.0$  V.

<sup>26.</sup> Guaranteed by design and characterization.

# **ELECTRICAL CHARACTERISTICS - VOLTAGE VERSION 3.3 V**

 $(-40^{\circ}C \leq T_{J} \leq 85^{\circ}C; \ V_{IN} = 4.3 \ V; \ I_{OUT} = 1 \ mA, \ C_{IN} = C_{OUT} = 1.0 \ \mu F, \ unless otherwise noted. Typical values are at T_{A} = +25^{\circ}C.) \ (Note 27)$ 

| Symbol              | Parameter   | Test Conditions   | Min   | Тур  | Max   | Unit  |
|---------------------|---|---|-------|------|-------|-------|
| V <sub>IN</sub>     | Operating Input Voltage                               |   | 2.2   | -    | 5.5   | V     |
| V <sub>OUT</sub>    | Output Voltage  | T <sub>A</sub> = +25°C  | 3.267 | 3.3  | 3.333 | V     |
|                     |   | $-40^{\circ}\text{C} \le \text{T}_{\text{J}} \le 85^{\circ}\text{C}$          | 3.234 | 3.3  | 3.366 |       |
| Line <sub>Reg</sub> | Line Regulation                                       | 4.3 V < V <sub>IN</sub> ≤ 5.5 V, I <sub>OUT</sub> = 1 mA                      | -     | 0.05 | 0.20  | %/V   |
| Load <sub>Reg</sub> | Load Regulation                                       | 0 mA < $I_{OUT} \le$ 150 mA, $V_{IN} = 4.3 \text{ V}$                         | -20   | 1    | 20    | mV    |
| $V_{DO}$            | Dropout Voltage                                       | I <sub>OUT</sub> = 150 mA (Note 28)   | -     | 180  | 250   | mV    |
| I <sub>OUT</sub>    | Output Current  | (Note 29)   | 150   | -    | -     | mA    |
| I <sub>SC</sub>     | Short Circuit Current Limit                           | V <sub>OUT</sub> = 0 V  | -     | 195  | -     | mA    |
| IQ                  | Quiescent Current                                     | I <sub>OUT</sub> = 0 mA   | -     | 0.5  | 0.9   | μΑ    |
| I <sub>STB</sub>    | Standby Current                                       | V <sub>EN</sub> = 0 V, T <sub>J</sub> = 25°C                                  | -     | 0.1  | 0.5   | μΑ    |
| V <sub>ENH</sub>    | EN Pin Threshold Voltage                              | EN Input Voltage "H"  | 1.2   | -    | -     | V     |
| V <sub>ENL</sub>    | EN Pin Threshold Voltage                              | EN Input Voltage "L"  | -     | -    | 0.4   | V     |
| I <sub>EN</sub>     | EN Pull Down Current                                  | V <sub>EN</sub> ≤ V <sub>IN</sub> ≤ 5.5 V (Note 30)                           | -     | 10   | -     | nA    |
| PSRR                | Power Supply Rejection Ratio                          | $f$ = 1 kHz, $V_{IN}$ = 4.3 V + 200 mVpp Modulation $I_{OUT}$ = 150 mA        | -     | 41   | -     | dB    |
| V <sub>NOISE</sub>  | Output Noise Voltage                                  | $V_{IN}$ = 5.5 V, $I_{OUT}$ = 1 mA f = 100 Hz to 1 MHz, $C_{OUT}$ = 1 $\mu F$ | -     | 125  | -     | μVrms |
| $R_{LOW}$           | Active Output Discharge<br>Resistance (A option only) | V <sub>IN</sub> = 5.5 V, V <sub>EN</sub> = 0 V (Note 30)                      | -     | 100  | -     | Ω     |
| T <sub>SD</sub>     | Thermal Shutdown Temperature                          | Temperature Increasing from T <sub>J</sub> = +25°C (Note 30)                  | -     | 175  | -     | °C    |
| T <sub>SDH</sub>    | Thermal Shutdown Hysteresis                           | Temperature Falling from T <sub>SD</sub> (Note 30)                            | -     | 25   | -     | °C    |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

27.Performance guaranteed over the indicated operating temperature range by design and/or characterization production tested at

<sup>27.</sup>Performance guaranteed over the indicated operating temperature range by design and/or characterization production tested at T<sub>J</sub> = T<sub>A</sub> = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.
28. Characterized when V<sub>OUT</sub> falls 99 mV below the regulated voltage and only for devices with V<sub>OUT</sub> = 3.3 V.

<sup>29.</sup> Respect SOA

<sup>30.</sup> Guaranteed by design and characterization.

# **ELECTRICAL CHARACTERISTICS - VOLTAGE VERSION 3.6 V**

 $(-40^{\circ}C \leq T_{J} \leq 85^{\circ}C; \ V_{IN} = 4.6 \ V; \ I_{OUT} = 1 \ mA, \ C_{IN} = C_{OUT} = 1.0 \ \mu F, \ unless \ otherwise \ noted. \ Typical \ values \ are \ at \ T_{A} = +25^{\circ}C.) \ (Note \ 31)$ 

| Symbol              | Parameter  | Test Conditions   | Min   | Тур  | Max   | Unit  |
|---------------------|--|---|-------|------|-------|-------|
| V <sub>IN</sub>     | Operating Input Voltage                            |   | 2.2   | -    | 5.5   | V     |
| V <sub>OUT</sub>    | Output Voltage                                     | T <sub>A</sub> = +25°C  | 3.564 | 3.6  | 3.636 | V     |
|                     |  | $-40^{\circ}C \le T_{J} \le 85^{\circ}C$                                      | 3.528 | 3.6  | 3.672 |       |
| Line <sub>Reg</sub> | Line Regulation                                    | 4.6 V < V <sub>IN</sub> ≤ 5.5 V, I <sub>OUT</sub> = 1 mA                      | -     | 0.05 | 0.20  | %/V   |
| Load <sub>Reg</sub> | Load Regulation                                    | 0 mA < I <sub>OUT</sub> ≤ 150 mA, V <sub>IN</sub> = 4.6 V                     | -20   | 1    | 20    | mV    |
| $V_{DO}$            | Dropout Voltage                                    | I <sub>OUT</sub> = 150 mA (Note 32)   | -     | 170  | 240   | mV    |
| I <sub>OUT</sub>    | Output Current                                     | (Note 33)   | 150   | -    | -     | mA    |
| I <sub>SC</sub>     | Short Circuit Current Limit                        | V <sub>OUT</sub> = 0 V  | -     | 195  | -     | mA    |
| IQ                  | Quiescent Current                                  | I <sub>OUT</sub> = 0 mA   | -     | 0.5  | 0.9   | μΑ    |
| I <sub>STB</sub>    | Standby Current                                    | V <sub>EN</sub> = 0 V, T <sub>J</sub> = 25°C                                  | -     | 0.1  | 0.5   | μΑ    |
| V <sub>ENH</sub>    | EN Pin Threshold Voltage                           | EN Input Voltage "H"  | 1.2   | -    | -     | V     |
| $V_{ENL}$           | EN Pin Threshold Voltage                           | EN Input Voltage "L"  | -     | -    | 0.4   | V     |
| I <sub>EN</sub>     | EN Pull Down Current                               | V <sub>EN</sub> ≤ V <sub>IN</sub> ≤ 5.5 V (Note 34)                           | -     | 10   | -     | nA    |
| PSRR                | Power Supply Rejection Ratio                       | $f$ = 1 kHz, $V_{IN}$ = 4.6 V + 200 mVpp Modulation $I_{OUT}$ = 150 mA        | -     | 30   | -     | dB    |
| V <sub>NOISE</sub>  | Output Noise Voltage                               | $V_{IN}$ = 5.5 V, $I_{OUT}$ = 1 mA f = 100 Hz to 1 MHz, $C_{OUT}$ = 1 $\mu F$ | -     | 130  | -     | μVrms |
| R <sub>LOW</sub>    | Active Output Discharge Resistance (A option only) | V <sub>IN</sub> = 5.5 V, V <sub>EN</sub> = 0 V (Note 34)                      | -     | 100  | -     |       |
| T <sub>SD</sub>     | Thermal Shutdown Temperature                       | Temperature Increasing from T <sub>J</sub> = +25°C (Note 34)                  | -     | 175  | -     | °C    |
| T <sub>SDH</sub>    | Thermal Shutdown Hysteresis                        | Temperature Falling from T <sub>SD</sub> (Note 34)                            | -     | 25   | -     | °C    |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 31. Performance guaranteed over the indicated operating temperature range by design and/or characterization production tested at  $T_J = T_A = T_A$ 

<sup>25°</sup>C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.

32. Characterized when V<sub>OUT</sub> falls 108 mV below the regulated voltage and only for devices with V<sub>OUT</sub> = 3.6 V.

<sup>33.</sup> Respect SOA.

<sup>34.</sup> Guaranteed by design and characterization.

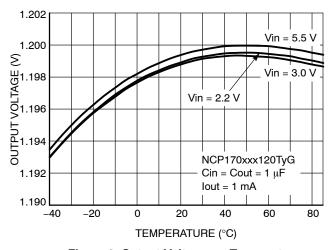


Figure 3. Output Voltage vs. Temperature, Vout = 1.2 V

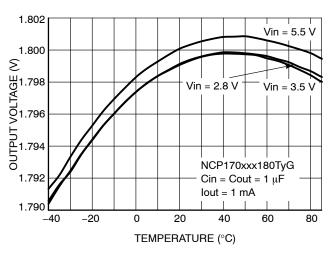


Figure 4. Output Voltage vs. Temperature, Vout = 1.8 V

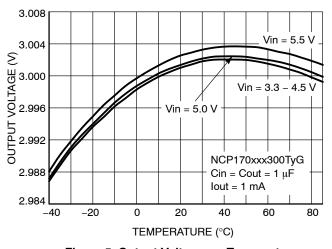


Figure 5. Output Voltage vs. Temperature, Vout = 3.0 V

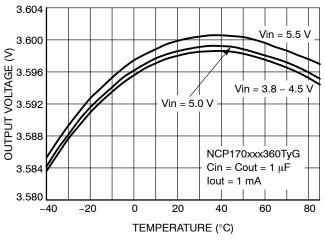


Figure 6. Output Voltage vs. Temperature, Vout = 3.6 V

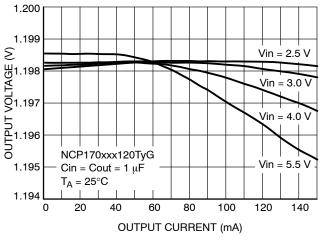


Figure 7. Output Voltage vs. Output Current, Vout = 1.2 V

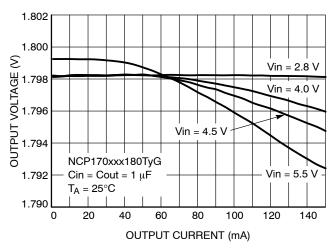


Figure 8. Output Voltage vs. Output Current, Vout = 1.8 V

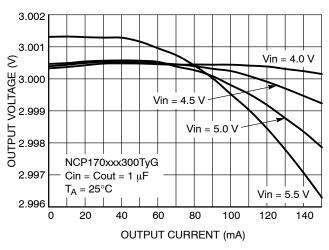


Figure 9. Output Voltage vs. Output Current, Vout = 3.0 V

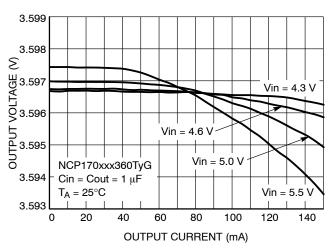


Figure 10. Output Voltage vs. Output Current, Vout = 3.6 V

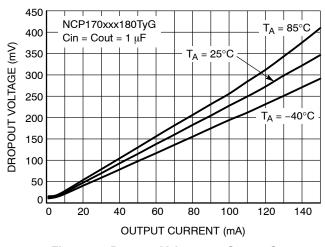


Figure 11. Dropout Voltage vs. Output Current, Vout = 1.8 V

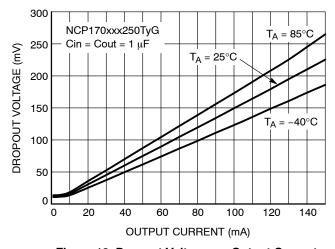


Figure 12. Dropout Voltage vs. Output Current, Vout = 2.5 V

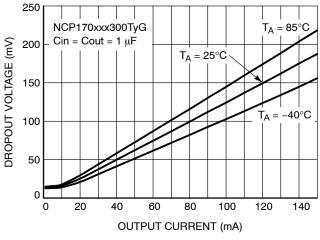


Figure 13. Dropout Voltage vs. Output Current, Vout = 3.0 V

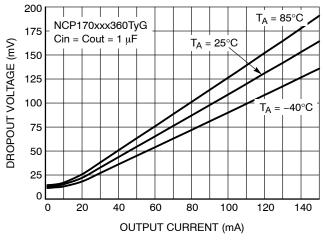


Figure 14. Dropout Voltage vs. Output Current, Vout = 3.6 V

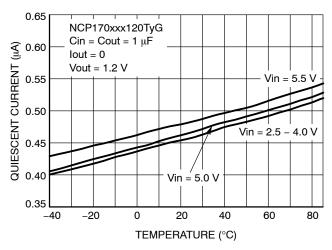


Figure 15. Quiescent Current vs. Temperature, Vout = 1.2 V

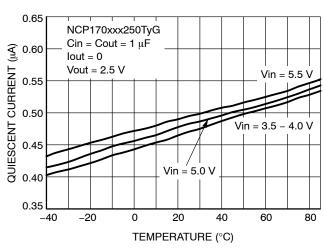


Figure 16. Quiescent Current vs. Temperature, Vout = 2.5 V

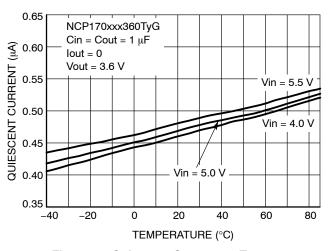


Figure 17. Quiescent Current vs. Temperature, Vout = 3.6 V

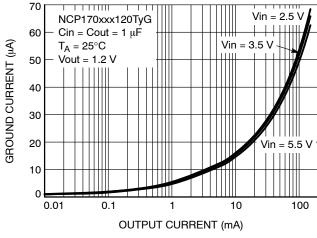


Figure 18. Ground Current vs. Output Current, Vout = 1.2 V

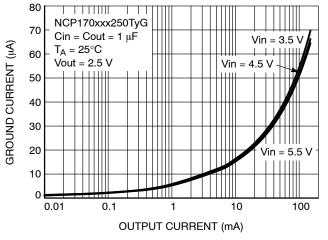


Figure 19. Ground Current vs. Output Current, Vout = 2.5 V

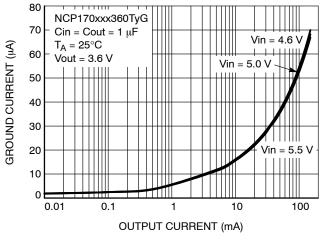


Figure 20. Ground Current vs. Output Current, Vout = 3.6 V

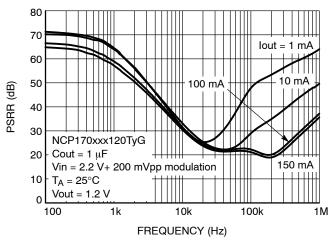


Figure 21. PSRR vs. Frequency, Vout = 1.2 V

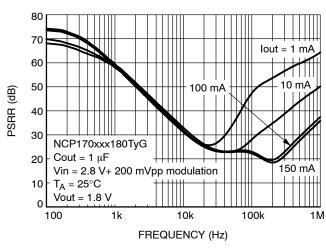


Figure 22. PSRR vs. Frequency, Vout = 1.8 V

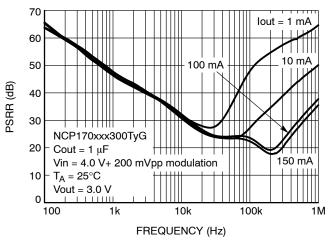


Figure 23. PSRR vs. Frequency, Vout = 3.0 V

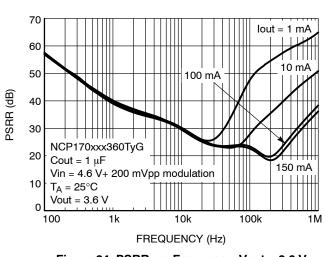


Figure 24. PSRR vs. Frequency, Vout = 3.6 V

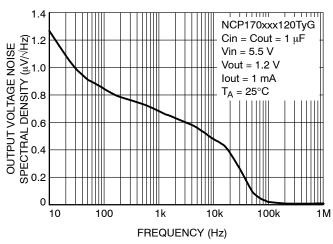


Figure 25. Output Voltage Noise Spectral Density, Vout = 1.2 V

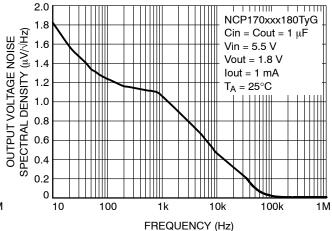


Figure 26. Output Voltage Noise Spectral Density, Vout = 1.8 V

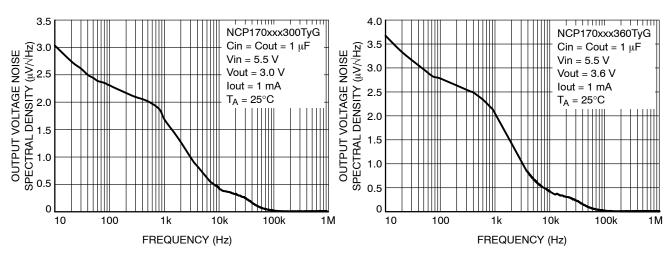


Figure 27. Output Voltage Noise Spectral Density, Vout = 3.0 V

Figure 28. Output Voltage Noise Spectral Density, Vout = 3.6 V

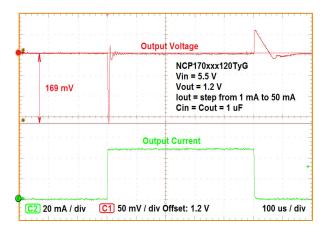


Figure 29. Load Transient Response at Load Step from 1 mA to 50 mA, Vout = 1.2 V

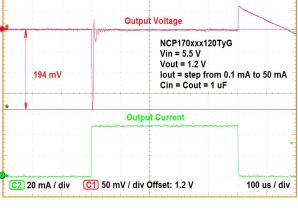


Figure 30. Load Transient Response at Load Step from 0.1 mA to 50 mA, Vout = 1.2 V

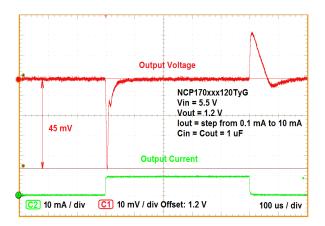


Figure 31. Load Transient Response at Load Step from 0.1 mA to 10 mA, Vout = 1.2 V

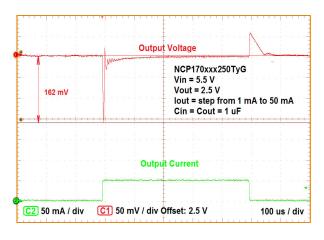


Figure 32. Load Transient Response at Load Step from 1 mA to 50 mA, Vout = 2.5 V

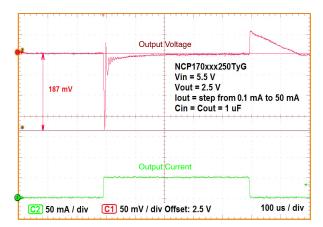


Figure 33. Load Transient Response at Load Step from 0.1 mA to 50 mA, Vout = 2.5 V

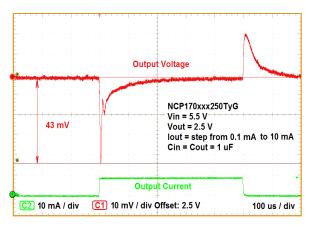


Figure 34. Load Transient Response at Load Step from 0.1 mA to 10 mA, Vout = 2.5 V

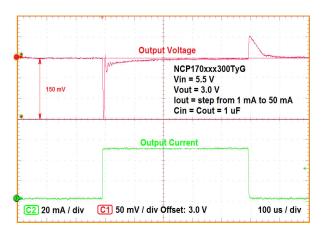


Figure 35. Load Transient Response at Load Step from 1mA to 50 mA, Vout= 3.0 V

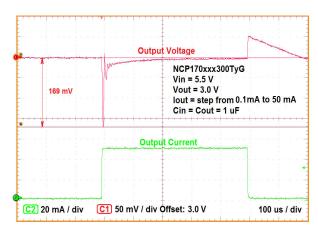


Figure 36. Load Transient Response at Load Step from 0.1 mA to 50 mA, Vout = 3.0 V

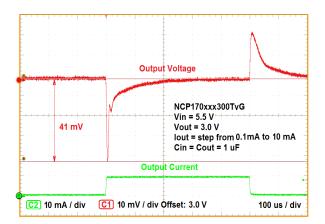


Figure 37. Load Transient Response at Load Step from 0.1 mA to 10 mA, Vout = 3.0 V

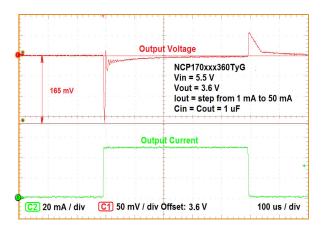


Figure 38. Load Transient Response at Load Step from 1 mA to 50 mA, Vout = 3.6 V

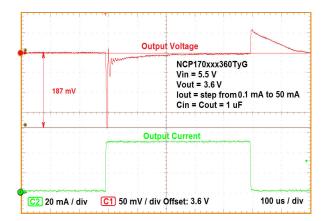


Figure 39. Load Transient Response at Load Step from 0.1 mA to 50 mA, Vout = 3.6 V

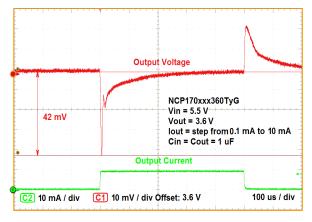


Figure 40. Load Transient Response at Load Step from 0.1 mA to 10 mA, Vout = 3.6 V

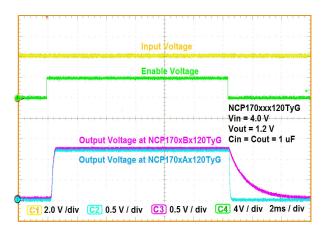


Figure 41. Output Voltage with and without Active Discharge Feature, Vout = 1.2 V

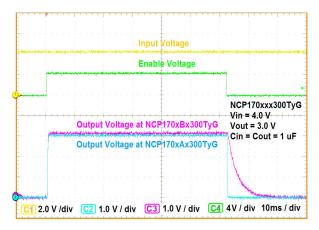


Figure 43. Output Voltage with and without Active Discharge Feature, Vout = 3.0 V

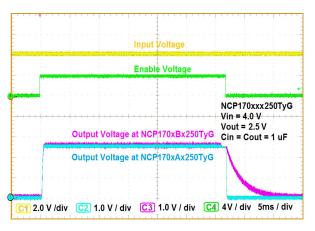


Figure 42. Output Voltage with and without Active Discharge Feature, Vout = 2.5 V

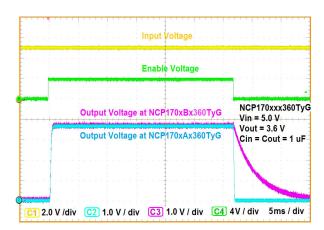


Figure 44. Output Voltage with and without Active Discharge Feature, Vout = 3.6 V

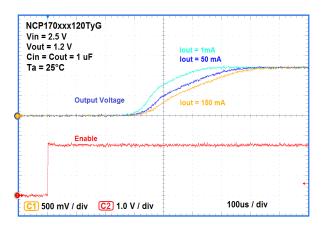


Figure 45. Enable Turn-on Response at Vout = 1.2 V

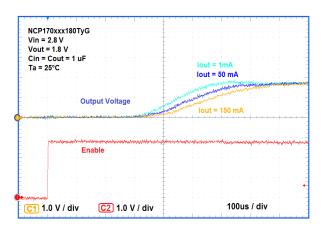


Figure 46. Enable Turn-on Response at Vout = 1.8 V

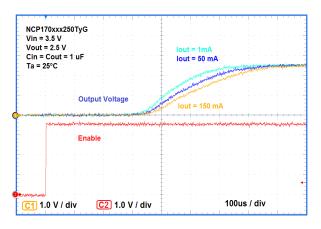


Figure 47. Enable Turn-on Response at Vout = 2.5 V

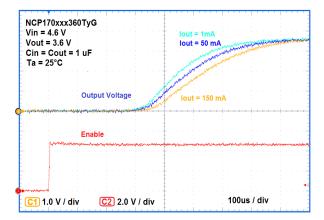


Figure 48. Enable Turn-on Response at Vout = 3.6 V

#### **APPLICATIONS INFORMATION**

#### General

The NCP170 is a high performance 150 mA Linear Regulator with Ultra Low IQ. This device delivers low Noise and high Power Supply Rejection Ratio with excellent dynamic performance due to employing the Dynamic Quiescent Current adjustment which assure ultra low  $\rm I_Q$  consumption at no – load state. These parameters make this device very suitable for various battery powered applications.

# Input Decoupling (CIN)

It is recommended to connect at least a 1  $\mu F$  Ceramic X5R or X7R capacitor between IN and GND pins of the device. This capacitor will provide a low impedance path for any unwanted AC signals or Noise superimposed onto constant Input Voltage. The good input capacitor will limit the influence of input trace inductances and source resistance during sudden load current changes.

Higher capacitance and lower ESR Capacitors will improve the overall line transient response.

#### Output Decoupling (COUT)

The NCP170 does not require a minimum Equivalent Series Resistance (ESR) for the output capacitor. The device is designed to be stable with standard ceramics capacitors with values of 1.0  $\mu F$  or greater up to 10  $\mu F$ . The X5R and X7R types have the lowest capacitance variations over temperature thus they are recommended. There is recommended connect the output capacitor as close as possible to the output pin of the regulator.

#### **Enable Operation**

The NCP170 uses the EN pin to enable /disable its device and to activate /deactivate the active discharge function at devices with this feature. If the EN pin voltage is pulled below 0.4 V the device is guaranteed to be disable. The active discharge transistor at the devices with Active Discharge Feature is activated and the output voltage VOUT is pulled to GND through an internal circuitry with effective resistance about 100 ohms.

If the EN pin voltage is higher than 1.2 V the device is guaranteed to be enabled. The internal active discharge circuitry is switched off and the desired output voltage is

available at output pin. In case the Enable function is not required the EN pin should be connected directly to input pin.

#### **Thermal Shutdown**

When the die temperature exceeds the Thermal Shutdown point (TSD = 175°C typical) the device goes to disabled state and the output voltage is not delivered until the die temperature decreases to 150°C. The Thermal Shutdown feature provides a protection from a catastrophic device failure at accidental overheating. This protection is not intended to be used as a substitute for proper heat sinking.

#### Power Dissipation and Heat sinking

The maximum power dissipation supported by the device is dependent upon board design and layout. Mounting pad configuration on the PCB, the board material, and the ambient temperature affect the rate of junction temperature rise for the part. For reliable operation, junction temperature should be limited to +125°C. The maximum power dissipation the NCP170 device can handle is given by:

$$P_{D(MAX)} = \frac{\left[T_{J(MAX)} - T_{A}\right]}{R_{\theta JA}}$$
 (eq. 1)

The power dissipated by the NCP170 device for given application conditions can be calculated from the following equations:

$$P_{D} \approx V_{IN} (I_{GND}(I_{OUT})) + I_{OUT} (V_{IN} - V_{OUT}) \qquad (eq. 2)$$

or

$$V_{\text{IN(MAX)}} \approx \frac{P_{\text{D(MAX)}} + (V_{\text{OUT}} \times I_{\text{OUT}})}{I_{\text{OUT}} + I_{\text{GND}}}$$
 (eq. 3)

#### Hints

VIN and GND printed circuit board traces should be as wide as possible. When the impedance of these traces is high, there is a chance to pick up noise or cause the regulator to malfunction. Place external components, especially the output capacitor, as close as possible to the NCP170, and make traces as short as possible.

# **ORDERING INFORMATION**

| Device          | Nominal<br>Output Voltage | Marking | Active<br>Discharge          | Package            | Shipping <sup>†</sup> |
|-----------------|---------------------------|---------|------------------------------|--------------------|-----------------------|
| NCP170AMX120TCG | 1.2                       | AC      |                              |                    |                       |
| NCP170AMX135TCG | 1.35                      | AP      |                              |                    |                       |
| NCP170AMX150TCG | 1.5                       | AJ      |                              |                    |                       |
| NCP170AMX170TCG | 1.7                       | AT      | 1                            |                    |                       |
| NCP170AMX180TBG | 1.8                       | AD      |                              |                    |                       |
| NCP170AMX180TCG | 1.8                       | AD      |                              |                    |                       |
| NCP170AMX190TCG | 1.9                       | AL      |                              |                    |                       |
| NCP170AMX250TCG | 2.5                       | AE      |                              |                    |                       |
| NCP170AMX280TBG | 2.8                       | AF      | Yes                          |                    |                       |
| NCP170AMX280TCG | 2.8                       | AF      | res                          |                    |                       |
| NCP170AMX285TCG | 2.85                      | AK      |                              |                    |                       |
| NCP170AMX300TBG | 3.0                       | AA      |                              |                    |                       |
| NCP170AMX300TCG | 3.0                       | AA      | XDFN4 1.0 × 1.0<br>(Pb-Free) |                    |                       |
| NCP170AMX310TCG | 3.1                       | AN      |                              |                    |                       |
| NCP170AMX320TCG | 3.2                       | AQ      |                              |                    |                       |
| NCP170AMX330TBG | 3.3                       | AG      |                              | 0000 / Tara & Daal |                       |
| NCP170AMX330TCG | 3.3                       | AG      |                              | (Pb-Free)          | 3000 / Tape & Reel    |
| NCP170AMX360TCG | 3.6                       | AM      |                              |                    |                       |
| NCP170BMX120TCG | 1.2                       | 2C      |                              |                    |                       |
| NCP170BMX135TCG | 1.35                      | 2P      |                              |                    |                       |
| NCP170BMX150TCG | 1.5                       | 2J      |                              |                    |                       |
| NCP170BMX170TCG | 1.7                       | 2T      |                              |                    |                       |
| NCP170BMX180TCG | 1.8                       | 2D      |                              |                    |                       |
| NCP170BMX190TCG | 1.9                       | 2L      |                              |                    |                       |
| NCP170BMX250TCG | 2.5                       | 2E      | No.                          |                    |                       |
| NCP170BMX280TCG | 2.8                       | 2F      | No                           |                    |                       |
| NCP170BMX285TCG | 2.85                      | 2K      |                              |                    |                       |
| NCP170BMX300TCG | 3.0                       | 2A      |                              |                    |                       |
| NCP170BMX310TCG | 3.1                       | 2N      | 1                            |                    |                       |
| NCP170BMX320TCG | 3.2                       | 2Q      |                              |                    |                       |
| NCP170BMX330TCG | 3.3                       | 2G      | 1                            |                    |                       |
| NCP170BMX360TCG | 3.6                       | 2M      |                              |                    |                       |

# **ORDERING INFORMATION**

| Device          | Nominal<br>Output Voltage | Marking | Active<br>Discharge | Package              | Shipping <sup>†</sup>                  |
|-----------------|---------------------------|---------|---------------------|----------------------|--|
| NCP170AXV120T2G | 1.2                       | AC      |                     |                      |  |
| NCP170AXV135T2G | 1.35                      | AL      | 1                   |                      |  |
| NCP170AXV150T2G | 1.5                       | AJ      | 1                   |                      |  |
| NCP170AXV180T2G | 1.8                       | AD      | 1                   |                      |  |
| NCP170AXV190T2G | 1.9                       | AM      | 1                   |                      |  |
| NCP170AXV210T2G | 2.1                       | AK      | ] ,                 |                      |  |
| NCP170AXV250T2G | 2.5                       | AE      | Yes                 |                      |  |
| NCP170AXV280T2G | 2.8                       | AF      | 1                   |                      |  |
| NCP170AXV300T2G | 3.0                       | AA      | 1                   |                      |  |
| NCP170AXV310T2G | 3.1                       | AN      | 1                   |                      | 4000 / Tape & Reel<br>(Available Soon) |
| NCP170AXV330T2G | 3.3                       | АН      | 1                   | SOT-563<br>(Pb-Free) |  |
| NCP170AXV360T2G | 3.6                       | AG      | 1                   |                      |  |
| NCP170BXV120T2G | 1.2                       | 2C      |                     |                      |  |
| NCP170BXV135T2G | 1.35                      | 2L      | 1                   |                      |  |
| NCP170BXV150T2G | 1.5                       | 2J      | 1                   |                      |  |
| NCP170BXV180T2G | 1.8                       | 2D      | 1                   |                      |  |
| NCP170BXV190T2G | 1.9                       | 2M      | 1                   |                      |  |
| NCP170BXV250T2G | 2.5                       | 2E      | No                  |                      |  |
| NCP170BXV280T2G | 2.8                       | 2F      | 1                   |                      |  |
| NCP170BXV300T2G | 3.0                       | 2A      | 1                   |                      |  |
| NCP170BXV310T2G | 3.1                       | 2N      | 1                   |                      |  |
| NCP170BXV330T2G | 3.3                       | 2H      | 1                   |                      |  |
| NCP170ASN120T2G | 1.2                       | GCG     |                     |                      |  |
| NCP170ASN150T2G | 1.5                       | GCH     | 1                   | TSOP-5<br>(Pb-Free)  |  |
| NCP170ASN180T2G | 1.8                       | GCF     | 1                   |                      |  |
| NCP170ASN250T2G | 2.5                       | GCE     | Yes                 |                      | 3000 / Tape & Reel<br>(Available Soon) |
| NCP170ASN280T2G | 2.8                       | GCA     | 1                   | (1.5.1.100)          | (, wanabio coori)                      |
| NCP170ASN300T2G | 3.0                       | GCC     | 1                   |                      |  |
| NCP170ASN330T2G | 3.3                       | GCD     | 1                   |                      |  |

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

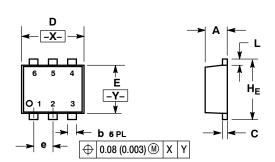
# **MECHANICAL CASE OUTLINE**





SOT-563, 6 LEAD CASE 463A ISSUE G

**DATE 23 SEP 2015** 



STYLE 1: PIN 1. EMITTER 1 2. BASE 1 3. COLLECTOR 2

4. EMITTER 2 5 BASE 2 6. COLLECTOR 1

STYLE 4: PIN 1. COLLECTOR COLLECTOR
 BASE 4. EMITTER 5. COLLECTOR

6. COLLECTOR

PIN 1. CATHODE 2. ANODE 3. CATHODE CATHODE
 ANODE 6. CATHODE

STYLE 7:

STYLE 10: PIN 1. CATHODE 1 2. N/C 3. CATHODE 2 4. ANODE 2

5 N/C 6. ANODE 1

STYLE 2: PIN 1. EMITTER 1 2. EMITTER2 3. BASE 2 4. COLLECTOR 2

5 BASE 1 6. COLLECTOR 1

STYLE 5: PIN 1. CATHODE CATHODE
 ANODE

4. ANODE 5. CATHODE 6. CATHODE

STYLE 8: PIN 1. DRAIN 2. DRAIN 3. GATE

4. SOURCE 5. DRAIN 6. DRAIN

STYLE 3: PIN 1. CATHODE 1 2. CATHODE 1 3. ANODE/ANODE 2 4. CATHODE 2 5. CATHODE 2

6. ANODE/ANODE 1

STYLE 6: PIN 1. CATHODE 2. ANODE 3. CATHODE 4. CATHODE 5. CATHODE

6. CATHODE

STYLE 9: PIN 1. SOURCE 1 2. GATE 1

3. DRAIN 2 4. SOURCE 2 5. GATE 2 6. DRAIN 1

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: MILLIMETERS

MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

|     | MILLIMETERS |         |      | INCHES |          |       |
|-----|-------------|---------|------|--------|----------|-------|
| DIM | MIN         | NOM     | MAX  | MIN    | NOM      | MAX   |
| Α   | 0.50        | 0.55    | 0.60 | 0.020  | 0.021    | 0.023 |
| b   | 0.17        | 0.22    | 0.27 | 0.007  | 0.009    | 0.011 |
| С   | 0.08        | 0.12    | 0.18 | 0.003  | 0.005    | 0.007 |
| D   | 1.50        | 1.60    | 1.70 | 0.059  | 0.062    | 0.066 |
| Е   | 1.10        | 1.20    | 1.30 | 0.043  | 0.047    | 0.051 |
| е   |             | 0.5 BSC |      | (      | 0.02 BS0 |       |
| L   | 0.10        | 0.20    | 0.30 | 0.004  | 0.008    | 0.012 |
| HE  | 1.50        | 1.60    | 1.70 | 0.059  | 0.062    | 0.066 |

#### **GENERIC MARKING DIAGRAM\***



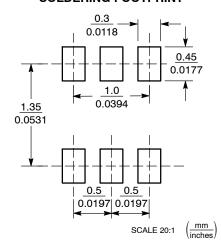
XX = Specific Device Code

= Month Code

= Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

# **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

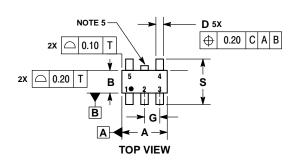
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| DESCRIPTION:     | SOT-563, 6 LEAD |  | PAGE 1 OF 1 |

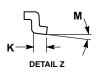
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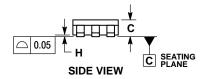


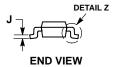
TSOP-5 **CASE 483** ISSUE M

**DATE 17 MAY 2016** 





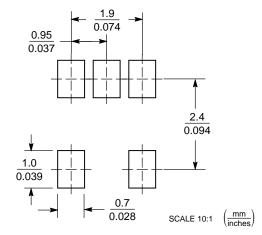




- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ASME
- THICKNESS, MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSION A.
- OPTIONAL CONSTRUCTION: AN ADDITIONAL TRIMMED LEAD IS ALLOWED IN THIS LOCATION. TRIMMED LEAD NOT TO EXTEND MORE THAN 0.2 FROM BODY.

|     | MILLIMETERS |      |  |  |
|-----|-------------|------|--|--|
| DIM | MIN MAX     |      |  |  |
| Α   | 2.85        | 3.15 |  |  |
| В   | 1.35        | 1.65 |  |  |
| C   | 0.90        | 1.10 |  |  |
| D   | 0.25        | 0.50 |  |  |
| G   | 0.95 BSC    |      |  |  |
| Н   | 0.01 0.10   |      |  |  |
| J   | 0.10        | 0.26 |  |  |
| K   | 0.20        | 0.60 |  |  |
| M   | 0 °         | 10 ° |  |  |
| S   | 2.50        | 3.00 |  |  |

#### **SOLDERING FOOTPRINT\***



<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# **GENERIC MARKING DIAGRAM\***





= Pb-Free Package

XXX = Specific Device Code

XX = Specific Device Code = Date Code = Assembly Location

= Year

= Work Week = Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

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| <b>DOCUMENT</b> | NUMBER: |
|-----------------|---------|
| 98ARB18753      | С       |

PAGE 2 OF 2

| ISSUE | REVISION  | DATE        |
|-------|---|-------------|
| 0     | INITIATED NEW MECHANICAL OUTLINE #483. REQ BY WL CHIN/L. RENNICK.   | 28 OCT 1998 |
| А     | UPDATE OUTLINE DRAWING TO CORRECT DIN "C" (SHOULD BE FROM TIP OF LID TO TOP OF PKG). DIM IN TABLE INCORRECTLY LISTED TO G, F TO H, H TO J, N TO L & R TO M. REQ BY F. PADILLA | 13 NOV 1998 |
| В     | CHANGE OF LEGAL ONWERSHIP FROM MOTOROLA TO ON SEMICONDUCTOR. REQ BY A. GARLINGTON   | 20 APR 2001 |
| С     | ADDED NOTE "4". REQ BY S. RIGGS   | 27 JUN 2003 |
| D     | ADDED FOOTPRINT INFORMATION. UPDATED MARKING. REQ. BY D. JOERSZ   | 07 APR 2005 |
| Е     | CHANGED DEVICE MARKING FROM AWW TO AYW. REQ. BY J. MANES.   | 14 SEP 2005 |
| F     | UPDATED DRAWINGS TO LATEST JEDEC STANDARDS. ADDED NOTE 5. REQ. BY T. GURNETT.   | 07 JUN 2006 |
| G     | ADDED MARKING DIAGRAM FOR IC OPTION. REQ. BY J. MILLER.   | 21 FEB 2007 |
| Н     | CORRECTED MARKING DIAGRAM ERROR BY REVERSING ANALOG AND DISCRETE LABELS. REQ. BY GK SUA.  | 18 MAY 2007 |
| J     | CHANGED NOTE 4. REQ. BY A. GARLINGTON.  | 13 MAR 2013 |
| K     | REMOVED DIMENSION L AND ADDED DATUMS A AND B TO TOP VIEW. REQ. BY A. GARLINGTON.  | 19 APR 2013 |
| L     | REMOVED -02 FROM CASE CODE VARIANT. REQ. BY N. CALZADA.   | 23 SEP 2015 |
| М     | CHANGED DIMENSIONS A & B FROM BASIC TO MIN AND MAX VALUES. REQ. BY A. GARLINGTON.   | 17 MAY 2016 |
|       |   |             |
|       |   |             |
|       |   |             |
|       |   |             |

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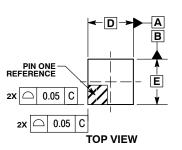
# **MECHANICAL CASE OUTLINE**

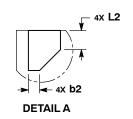


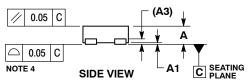


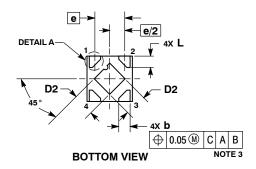
#### XDFN4 1.0x1.0, 0.65P CASE 711AJ **ISSUE A**

**DATE 13 NOV 2015** 

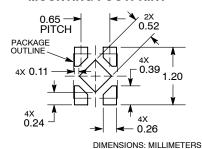








#### **RECOMMENDED MOUNTING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### NOTES:

- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

  2. CONTROLLING DIMENSION: MILLIMETERS.

  3. DIMENSION 6 APPLIES TO PLATED TERMINAL
- AND IS MEASURED BETWEEN 0.15 AND
- 0.20 mm FROM THE TERMINAL TIPS. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

|     | MILLIMETERS |      |  |  |
|-----|-------------|------|--|--|
| DIM | MIN         | MAX  |  |  |
| Α   | 0.33        | 0.43 |  |  |
| A1  | 0.00        | 0.05 |  |  |
| А3  | 0.10        | REF  |  |  |
| b   | 0.15 0.25   |      |  |  |
| b2  | 0.02        | 0.12 |  |  |
| D   | 1.00 BSC    |      |  |  |
| D2  | 0.43 0.53   |      |  |  |
| E   | 1.00 BSC    |      |  |  |
| е   | 0.65 BSC    |      |  |  |
| L   | 0.20 0.30   |      |  |  |
| L2  | 0.07 0.17   |      |  |  |

### **GENERIC MARKING DIAGRAM\***



XX = Specific Device Code = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking.

Pb-Free indicator, "G" or microdot " ■", may or may not be present.

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| DESCRIPTION:     | XDFN4, 1.0X1.0, 0.65P |   | PAGE 1 OF 1 |

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